

# **STPS40M120C**

# Datasheet

# 120 V power Schottky rectifier





TO-220AB

## **Features**

- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation
- ECOPACK<sup>®</sup>2 compliant

# **Applications**

- Switching diode
- SMPS
  - DC/DC converter
- LED lighting
- Notebook adapter

### **Description**

This Schottky rectifier is suited for high frequency switch mode power supply.

The voltage drop versus leakage current trade-off is in keeping with medium power hi-density adapter design.

Packed in TO-220AB, the STPS40M120C is optimized for use in notebook, game station and desktop adaptors, providing in these applications a good efficiency at both low and high load.

Product status link			
STPS40M120C			
Product summary			
Symbol Value			
I <sub>F(AV)</sub>	2 x 20 A		
<b>V<sub>RRM</sub></b> 120 V			
<b>T</b> <sub>j</sub> (max.) 150 °C			
<b>V<sub>F</sub> (typ.)</b> 0.61 ∨			

# 1 Characteristics

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# Table 1. Absolute Ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter				Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage			120	V
I <sub>F(RMS)</sub>	Forward rms current			30	Α
	$F(AV)$ Average forward current, $\delta = 0.5$	T <sub>C</sub> = 130 °C	Per diode	20	
IF(AV)		T <sub>C</sub> = 120 °C	Per device	40	A
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinu	t <sub>p</sub> = 10 ms sinusoidal		Α
P <sub>ARM</sub>	Repetitive peak avalanche power	t <sub>p</sub> = 10 μs , T <sub>j</sub> =	t <sub>p</sub> = 10 μs , T <sub>j</sub> = 125 °C		W
T <sub>stg</sub>	Storage temperature range			-65 to +175	°C
Tj	Maximum operating junction temperature <sup>(1)</sup>			150	°C

1.  $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

### Table 2. Thermal resistance parameters

Symbol	Parameter		Value	Unit
Du a s	R <sub>th(j-c)</sub> Junction to case	Per diode	1.10	°C/W
⊾th(j-c)		Total	0.80	
R <sub>th(c)</sub>	Coupling		0.50	

## When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th}(j-c)} \text{ (per diode)} + P_{\text{(diode2)}} \times R_{\text{th}(c)}$ 

For more information, please refer to the following application note :

AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode	<del>!</del> )
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Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_ (1)	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	75	370	μA
IR (1)		T <sub>j</sub> = 125 °C		-	25	70	mA
	V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 5 A	-	0.44	0.49	
V (2)		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 10 A	-	0.52	0.57	V
VF		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A	-		0.79	v
		T <sub>j</sub> = 125 °C	IF - 20 A	-	0.61	0.67	

1. Pulse test:  $t_p = 5 ms$ ,  $\delta < 2\%$ 

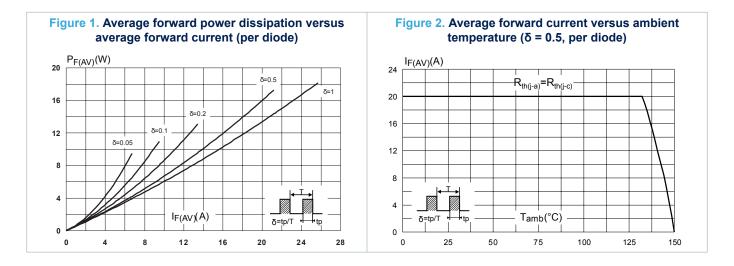
2. Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%

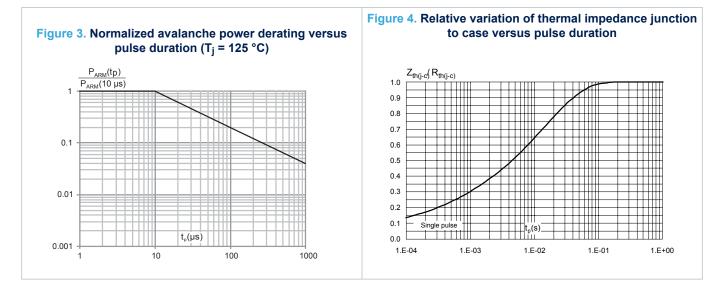
To evaluate the conduction losses, use the following equation: P = 0.54 x  $I_{F(AV)}$  + 0.0065 x  $I_{F}$  <sup>2</sup> (RMS) For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

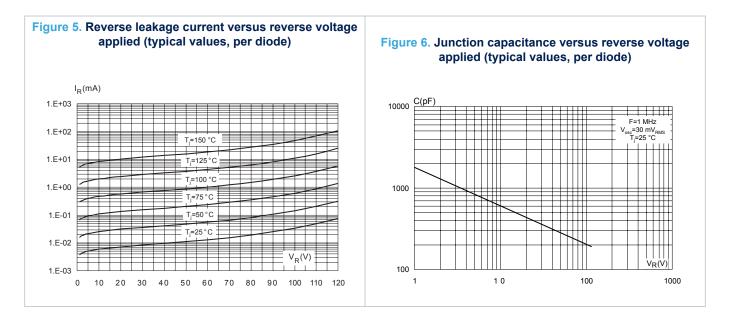
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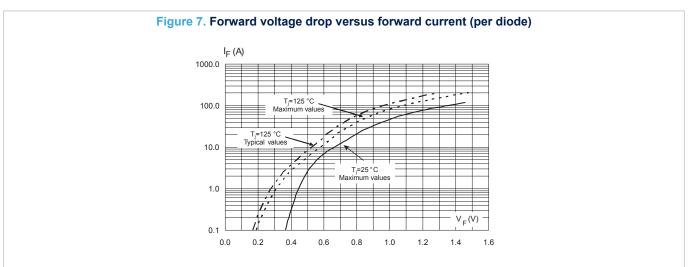
# **1.1 Characteristics (curves)**











# 2 Package information

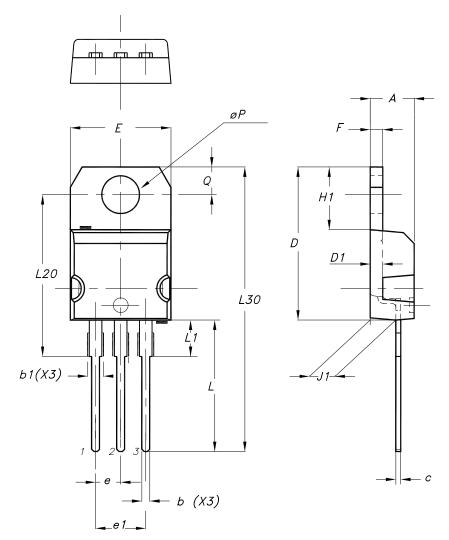
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In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

# 2.1 TO-220AB package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

## Figure 8. TO-220AB package outline



		Dimer	isions	
Ref.	Millir	Millimeters		ference only)
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
С	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.2	7 typ.	0.050 typ.	
E	10.00	10.40	0.394	0.409
е	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.4	16.40 typ.		З typ.
L30	28.9	28.90 typ.		3 typ.
θΡ	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116

### Table 4. TO-220AB package mechanical data



# **3** Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40M120CT	PS40M120CT	TO-220AB	1.95 g	50	Tube

# **Revision history**

### Table 6. Document revision history

Date	Version	Changes
02-Apr-2012	1	First issue.
27-Jun-2018	2	Updated Table 1. Absolute Ratings (limiting values, per diode, at 25 °C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j$ = 125 °C). Removed TO-220AB narrow leads and I <sup>2</sup> PAK package information.
13-Nov-2018	3	Updated Table 5.



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